HYBRID SOLID STATE RELAY



Features

- High Voltage/Low Resistance Figure of Merit
- · Single Pole, Single Throw Form A
- Wide Band Gap Semiconductors for low Resistance
- Magnetically Coupled Command for fast response
- No Optocoupler, no optocoupler issues
- Selectable Continuous or Mag Latch Function
- Logic Level Drive
- Rugged Hermetic Package

Specifications

Bias Input Voltage 4.7 to 5.3 VDC

Bias input current 30 mA typical, 50 mA maximum

Command input 1 mA compatible with TTL logic levels

Input/output and all pins to case isolation 10 Megohms mimimum at 500V

Power Dissipation 4 watts at maximum rated case temperature

Case temperature range:

Operating 0°C to +55°C (EU Grade)

Operating -55°C to +85°C (M Grade)

Operating -55°C to +125°C (E Grade)

Storage -65°C to +150°C

Weight 30 grams typical

For continuous operation, connect 5 VDC to bias pins and bias ground pins to control ground.

Apply +5 VDC to command input to energize the SSR. With +5 VDC connected to +5 VDC, connect pin 15 to bias return to disable.

Power Dissipation:

Total steady state power dissipation of the model 3807 and 3808 is limited to 4 watts provided the baseplate temperature is limited to the rated temperature.



Modular Devices, Inc.

Power Conversion for Space and Military/Aerospace

MODEL 3807/3808

Model 3807 is a SPST 300V/5A form A (normally open when de-energized) SSR. Model 3808 is a SPST 50V/10A form A (normally open when de-energized) SSR.

Both uses a Wide Bandgap power semiconductor for high performance, are is magnetically coupled and can be user configured for continuous or pulse latching.

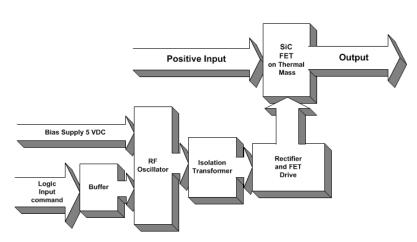
Wide band gap (WBG) semiconductors such as GaN (Gallium Nitride) and SiC (Silicon Carbide) provide an order of magnitude improvement in SSR voltage drop compared to SSRs using Silicon based power devices.

Also, WBG semiconductors of a given dimension can withstand higher electric fields than Silicon semiconductors, the physical dimensions of these WBG parts are considerably smaller than their Silicon competitors. The result of WBG is much lower channel resistances and reduced drive requirements.

Many SSR manufacturers drive their SSR power device with opto couplers consisting of an LED emitter driving a multi-diode photo-voltaic stack.

A disadvantage of opto coupled drive is slow turn on and turn off response and variation of on and off times with temperature.

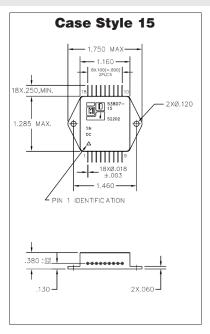
MDI replaces the optocoupler function with a tiny, transformer isolated RF drive signal. This solves the opto coupler problems and gives faster, more temperature stable operation.



		Model 3	807 300V/5A F	orm A SSR
PARAMETER	CONDITION	MIN	TYP	MA
Contact Rating V	Max	_	_	500V
Contact Rating I	Max	_	_	5A
Contact Resistance, 25°C	Energized	_	0.15Ω	0.25Ω
Contact Resistance, 125°C	Energized	_	0.3 Ω	0.5Ω
Leakage Current, 500V, 25°C	Off	_	_	60µA
Leakage Current, 500V, 125°C	Off	_	_	100μΑ
Bias Voltage	_	4.7V	5.0V	5.3V
Bias Current	_	_	30mA	50mA
Command on	_	3.0V	5.0V	6.0V
Command Current	_	0.1mA	0.8mA	2.0mA
Delay Time, energized	_	_	12µS	30µS
Delay Time, de-energized	_	_	20µS	40µS
Energize Time, dynamic	_	_	12µS	30µS
De-energize time, dynamic	_	_	5µS	20µS

Model 3808 50V/10A Form A SSR					
PARAMETER	CONDITION	MIN	TYP	MA	
Contact Rating V	Max	_	_	100V	
Contact Rating I	Max	_	_	10A	
Contact Resistance, 25°C	Energized	_	0.075Ω	0.1Ω	
Contact Resistance, 125°C	Energized	_	0.15 Ω	0.2Ω	
Leakage Current, 500V, 25°C	Off	_	_	60μA	
Leakage Current, 500V, 125°C	Off	_	_	100μΑ	
Bias Voltage	_	4.7V	5.0V	5.3V	
Bias Current	_	_	30mA	50mA	
Command on	_	3.0V	5.0V	6.0V	
Command Current	_	0.1mA	0.8mA	2.0mA	
Delay Time, energized	_	_	12µS	30μS	
Delay Time, de-energized	_	_	20μS	40μS	
Energize Time, dynamic	_	_	12µS	30μS	
De-energize time, dynamic	_	_	5µS	20µS	

HYBRID SOLID STATE RELAY



200	7 D:	0.4014
		n Out Chart
Pin	1	Cext Rise Time Capacitor
Pin	2	N/C
Pin	3	+Switched Input
Pin	4	+Switched Input
Pin	5	+Switched Input
Pin	6	N/C
Pin	7	+Switched Input Return
Pin	8	+Switched Input Return
Pin	9	+Switched Input Return
Pin	10	Bias +5VDC
Pin	11	Bias +5VDC
Pin	12	Bias Return
Pin	13	Bias Return
Pin	14	N/C
Pin	15	Ground To Disable
Pin	16	Command Input +
Pin	17	N/C
Pin	18	N/C

3808 Pi	n Out Chart
Pin 1	Cext Rise Time Capacitor
Pin 2	N/C
Pin 3	+Switched Input
Pin 4	+Switched Input
Pin 5	+Switched Input
Pin 6	N/C
Pin 7	+Switched Input Return
Pin 8	+Switched Input Return
Pin 9	+Switched Input Return
Pin 10	Bias +5VDC
Pin 11	Bias +5VDC
Pin 12	Bias Gnd
Pin 13	Bias Gnd
Pin 14	N/C
Pin 15	Ground To Disable
Pin 16	Command Input +
Pin 17	N/C
Pin 18	N/C

Model No.	Case Style	Pin Count	Mounting
3807/3808	15	18	Seam Weld Chassis Mount with Flange

GRADE LEVELS:

Please specify grade level for your application. EU grade units will be shipped if no option is specified.

EU Engineering Units

M +85°C military/aerospace

E +125°C military/aerospace

For Heat Removal and Mounting Recommendations See MDI application notes on mounting considerations for DC-DC Converters

